

Transient Voltage Suppression Diodes

5.0SMDJ Series



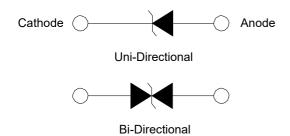
Description

Transient Voltage Suppressor (TVS) is a circuit protection component that either attenuates (reduces) or filters a transient voltage spike (overvoltage), TVS diodes provide critical protection by going into avalanche breakdown within no more than a few nanoseconds after a strike, clamping the transient voltage, and routing its current to the ground.

Applications

- Communication Equipment
- Security & Protection
- Industrial Control Equipment
- Power Supply
- **Automotive Electronics**
- New Energy
- Lightning Protection

Functional Diagram

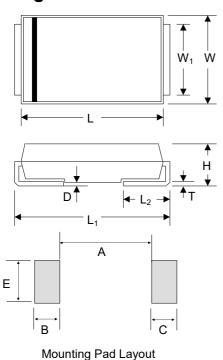


Features

- Low incremental surge resistance
- Excellent clamping capability
- Low profile package with built-in strain relief
- Typical I_R less than 5.0 µA above 22 V
- 5000 W peak pulse power capability with a 10/1000 μs Waveform, repetition rate (duty cycle): 0.01%
- For surface mounted applications to optimize board space
- Typical failure mode is short from over-specified voltage or current
- IEC 61000-4-2 ESD 30 kV (Air), 30 kV (Contact)
- EFT protection of data lines in accordance with IEC 61000
- Very fast response time
- Glass passivated chip junction
- High temperature to reflow soldering guaranteed: 260 °C/40sec
- V_{BR} @ $T_J = V_{BR}$ @25 °C x (1+ α T x (T_J 25)) (αT:Temperature Coefficient, typical value is 0.1%)
- Plastic package is flammability rated V-0 per Underwriters Laboratories
- Meet MSL level1, per J-STD-020
- Matte tin lead-free plated
- Halogen free and RoHS compliant
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/JEDEC J-STD-609A.01)

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Package Outline Dimensions (DO-214AB)



Symbol	Millime	eters	Inc	hes	
Symbol	Min.	Max.	Min.	Max.	
L	6.60	7.11	0.260	0.280	
W	5.59	6.22	0.220	0.245	
W ₁	2.90	3.20	0.114	0.126	
Н	2.06	2.62	0.079	0.103	
Т	0.152	0.305	0.006	0.012	
L ₁	7.75	8.13	0.305	0.320	
L ₂	0.76	1.52	0.030	0.060	
D	-	0.203	-	0.008	
Α	-	4.20	-	0.165	
В	2.40	-	0.094	-	
С	2.40	-	0.094	-	
Е	3.30	-	0.129	-	

Maximum Ratings and Characteristics

(Ratings at 25 °C ambient temperature unless otherwise specified.)

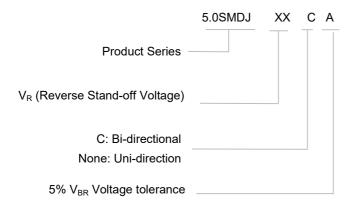
Parameter	Symbol	Value	Unit
Peak Pulse Power Dissipation at T _L =25 °C by 10/1000 μs waveform ⁽¹⁾⁽²⁾ (Fig.2)	P _{PPM}	5000	W
Peak Power Dissipation on Infinite Heat Sink at T _L =50 °C	P _D	6.5	W
Peak Forward Surge Current,8.3 ms single half sine wave superimposed on rated load (JEDEC Method) ⁽³⁾	I _{FSM}	300	А
Maximum Instantaneous Forward Voltage at 100 A for Unidirectional Only	V _F	5.0	V
Operating Junction and Storage Temperature Range	$T_{J,}T_{STG}$	-55 to +150	°C
Typical Thermal Resistance Junction to Lead	R _{0JL}	15	°C/W
Typical Thermal Resistance Junction to Ambient	$R_{\theta JA}$	75	°C/W

Notes

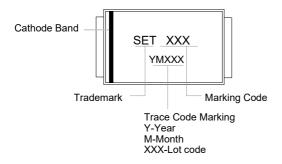
- Non-repetitive current pulse, per Fig. 4 and derated above T_J (initial)=25 °C per Fig. 3. Mounted on 8.0 mm 2 land areas.
- Measured of 8.3 ms single half sine-wave or equivalent square wave, duty cycle=4 pulses per minute maximum.

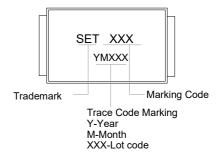


Part Numbering System



Marking





Transient Voltage Suppression Diodes

5.0SMDJ Series

Electrical Characteristics (T_A=25 °C unless otherwise noted)

Part Number		Device Marking Code		Volt	down age @I _T	Test Current I _T	Current Stand-off	Max. Reverse Leakage I _R @V _R	Max. Peak Pulse Current I _{PPM}	Max. Clamping Voltage V _C @l _{PPM}
				Min	Max		- K	-KC - K	(10/1000 µs)	(10/1000µs)
Uni	Bi	Uni	Bi	(1	/)	(mA)	(V)	(μΑ)	(A)	(V)
5.0SMDJ12A	5.0SMDJ12CA	5PEP	5BEP	13.30	14.70	10	12.00	800.00	252.00	19.90
5.0SMDJ13A	5.0SMDJ13CA	5PEQ	5BEQ	14.40	15.90	10	13.00	500.00	233.00	21.50
5.0SMDJ14A	5.0SMDJ14CA	5PER	5BER	15.60	17.20	10	14.00	200.00	216.00	23.20
5.0SMDJ15A	5.0SMDJ15CA	5PES	5BES	16.70	18.50	1	15.00	100.00	205.00	24.40
5.0SMDJ16A	5.0SMDJ16CA	5PET	5BET	17.80	19.70	1	16.00	50.00	193.00	26.00
5.0SMDJ17A	5.0SMDJ17CA	5PEU	5BEU	18.90	20.90	1	17.00	20.00	181.00	27.60
5.0SMDJ18A	5.0SMDJ18CA	5PEV	5BEV	20.00	22.10	1	18.00	10.00	172.00	29.20
5.0SMDJ20A	5.0SMDJ20CA	5PEW	5BEW	22.20	24.50	1	20.00	5.00	155.00	32.40
5.0SMDJ22A	5.0SMDJ22CA	5PEX	5BEX	24.40	26.90	1	22.00	5.00	141.00	35.50
5.0SMDJ24A	5.0SMDJ24CA	5PEZ	5BEZ	26.70	29.50	1	24.00	5.00	129.00	38.90
5.0SMDJ26A	5.0SMDJ26CA	5PFE	5BFE	28.90	31.90	1	26.00	5.00	119.00	42.10
5.0SMDJ28A	5.0SMDJ28CA	5PFG	5BFG	31.10	34.40	1	28.00	5.00	110.00	45.40
5.0SMDJ30A	5.0SMDJ30CA	5PFK	5BFK	33.30	36.80	1	30.00	5.00	103.00	48.40
5.0SMDJ33A	5.0SMDJ33CA	5PFM	5BFM	36.70	40.60	1	33.00	5.00	93.90	53.30
5.0SMDJ36A	5.0SMDJ36CA	5PFP	5BFP	40.00	44.20	1	36.00	5.00	86.10	58.10
5.0SMDJ40A	5.0SMDJ40CA	5PFR	5BFR	44.40	49.10	1	40.00	5.00	77.60	64.50
5.0SMDJ43A	5.0SMDJ43CA	5PFT	5BFT	47.80	52.80	1	43.00	5.00	72.10	69.40
5.0SMDJ45A	5.0SMDJ45CA	5PFV	5BFV	50.00	55.30	1	45.00	5.00	68.80	72.70
5.0SMDJ48A	5.0SMDJ48CA	5PFX	5BFX	53.30	58.90	1	48.00	5.00	64.70	77.40
5.0SMDJ51A	5.0SMDJ51CA	5PFZ	5BFZ	56.70	62.70	1	51.00	5.00	60.70	82.40
5.0SMDJ54A	5.0SMDJ54CA	5PGE	5BGE	60.00	66.30	1	54.00	5.00	57.50	87.10

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Part Number		Device Marking Code		Breakdown Voltage V _{BR} @I _T		Test Current I _T	Reverse Stand-off Voltage	Max. Reverse Leakage	Max. Peak Pulse Current	Max. Clamping Voltage
				Min	Max		V _R	I _R @V _R	I _{PPM} (10/1000 μs)	V _C @I _{PPM} (10/1000μs)
Uni	Bi	Uni	Bi	((V)	(mA)	(V)	(μΑ)	(A)	(V)
5.0SMDJ58A	5.0SMDJ58CA	5PGG	5BGG	64.40	71.20	1	58.00	5.00	53.50	93.60
5.0SMDJ60A	5.0SMDJ60CA	5PGK	5BGK	66.70	73.70	1	60.00	5.00	51.70	96.80
5.0SMDJ64A	5.0SMDJ64CA	5PGM	5BGM	71.10	78.60	1	64.00	5.00	48.60	103.00
5.0SMDJ70A	5.0SMDJ70CA	5PGP	5BGB	77.80	86.00	1	70.00	5.00	44.30	113.00
5.0SMDJ75A	5.0SMDJ75CA	5PGR	5BGR	83.30	92.10	1	75.00	5.00	41.40	121.00
5.0SMDJ78A	5.0SMDJ78CA	5PGT	5BGT	86.70	95.80	1	78.00	5.00	39.70	126.00
5.0SMDJ85A	5.0SMDJ85CA	5PGV	5BGV	94.40	104.00	1	85.00	5.00	36.50	137.00
5.0SMDJ90A	5.0SMDJ90CA	5PGX	5BGX	100.00	111.00	1	90.00	5.00	34.30	146.00
5.0SMDJ100A	5.0SMDJ100CA	5PGZ	5BGZ	111.00	123.00	1	100.00	5.00	30.90	162.00
5.0SMDJ110A	5.0SMDJ110CA	5PHE	5BHE	122.00	135.00	1	110.00	5.00	28.30	177.00
5.0SMDJ120A	5.0SMDJ120CA	5PHG	5BHG	133.00	147.00	1	120.00	5.00	26.00	193.00
5.0SMDJ130A	5.0SMDJ130CA	5PHK	5BHK	144.00	159.00	1	130.00	5.00	24.00	209.00
5.0SMDJ140A	5.0SMDJ140CA	5PHL	5BHL	156.00	172.00	1	140.00	5.00	22.20	226.00
5.0SMDJ150A	5.0SMDJ150CA	5PHM	5BHM	167.00	185.00	1	150.00	5.00	20.60	243.00
5.0SMDJ160A	5.0SMDJ160CA	5PHP	5BHB	178.00	197.00	1	160.00	5.00	19.30	259.00
5.0SMDJ170A	5.0SMDJ170CA	5PHR	5BHR	189.00	209.00	1	170.00	5.00	18.20	275.00

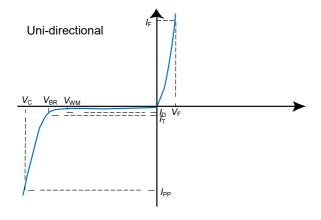
Notes:

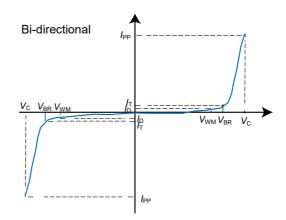
For bidirectional type having V_R of 20 volts and less, the I_R should be doubled.

For parts without A in the PN , the V_{BR} tolerance is \pm 10% and V_C is 5% higher than parts with A .The parts without A are currently available, but not recommended for new designs. The parts with A are preferred.



I-V Curve Characteristics





Performance Curve for Reference(T_A=25 °C unless otherwise noted)

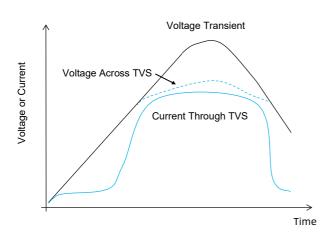


FIGURE 1 TVS Transients Clamping Waveform

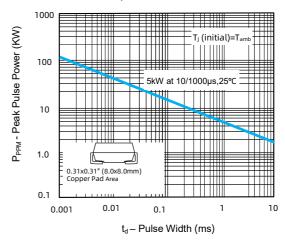


FIGURE 2 Peak Pulse Power Rating Curve



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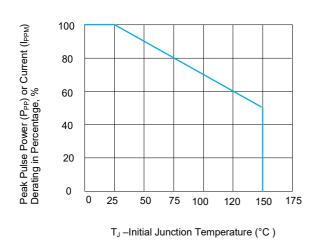
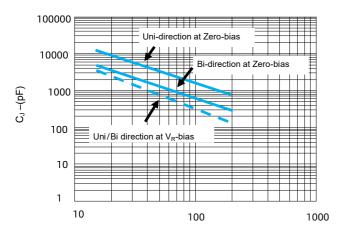


FIGURE 3 Peak Pulse Power Derating Curve



V_{BR} – Reverse Breakdown Voltage (V)

FIGURE 5 Typical Junction Capacitance

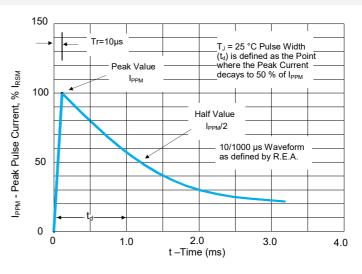


FIGURE 4 Pulse Waveform

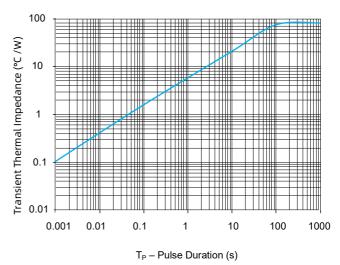


FIGURE 6 Typical Transient Thermal Impedance

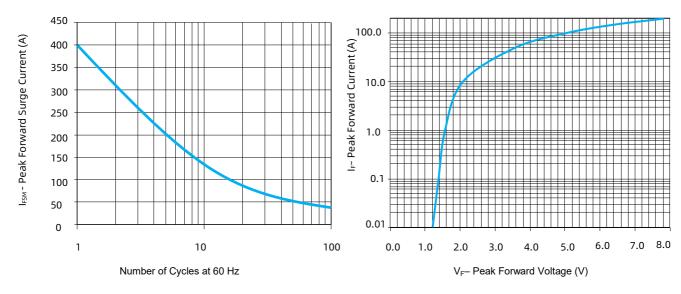


FIGURE 7 Maximum Non-Repetitive Forward Surge Current Uni-Directional only

FIGURE 8 Peak Forward Drop vs Peak Forward Current (Typical Values)



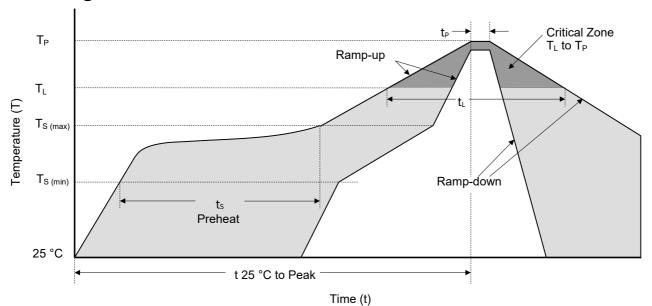
Environmental Specifications

High Temp. Storage	JESD22-A103			
HTRB	JESD22-A108			
Temperature Cycling	JESD22-A104			
MSL	JESDEC-J-STD-020, Level 1			
H3TRB	JESD22-A101			
RSH	JESD22-A111			

Physical Specifications

Weight	0.007 ounce,0.21 grams
Case	JESD22DO214AB. Molded plastic body over glass passivated junction
Polarity	Color band denotes positive end (cathode) except Bidirectional
Terminal	Matte Tin-plated leads, Solderability per JESD22-B102

Soldering Parameters

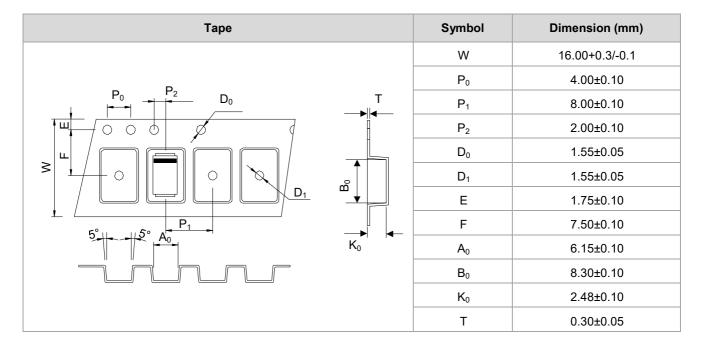


Reflowing Condition

Reflow Soldering	ng Parameters	Lead-Free Assembly			
	Temperature Min (T _{S (min)})	150 °C			
Pre-heat	Temperature Max (T _{S (max)})	200 °C			
	Time (min to max) (t _s)	60 ~ 120 seconds			
Average Ramp Up Rate (L	Average Ramp Up Rate (Liquidus Temp (TL) to Peak				
T _S (max) to T _L	T _S (max) to T _L Ramp-up Rate				
D 6	Temperature (T _L) (Liquidus)	217 °C			
Reflow	Time (min to max) (t _L)	60 ~ 150 seconds			
Peak Tempo	erature (T _P)	260 ^{+0/-5} °C			
Time of within 5 °C of Acti	ual Peak Temperature (t _P)	20 ~ 40 seconds			
Ramp-do	wn Rate	6 °C / second max.			
Time from 25 °C to	Peak Temperature	8 Minutes max.			
Do Not	Exceed	260 °C			



Packaging Information



Reel Size		13" Reel
A A	А	330 mm
Arbor hole Dia. Direction of Feed	С	13.2 mm
†	W ₁	16.4 mm

Part Number	Package	QTY (Reel)	Packaging Option	Packaging Specification
5.0SMDJ×××	DO-214AB	3000 PCS	Tape & Reel – 16 mm tape/13" reel	EIA STD RS-481

Transient Voltage Suppression Diodes



Glossary

Item	Description
v _c	Clamping Voltage Voltage across TVS in a region of low differential resistance that serves to limit the voltage across the device terminals.
V _R	Reverse Stand-off Voltage Maximum voltage that can be applied to the TVS without operation. NOTE: It is also shown as V_{WM} (maximum working voltage (maximum d.c. voltage)) and known as rated stand-off voltage (V_{so}).
I _R	Reverse Leakage Current Current measured at $V_{R.}$ NOTE: Also shown as I_{D} for stand-by current.
V BR	Breakdown Voltage Voltage across TVS at a specified current I_T in the breakdown region.
I _{PPM}	Rated Random Recurring Peak Impulse Current Maximum-rated value of random recurring peak impulse current that may be applied to a device.
P _{M(AV)}	Rated Average Power Dissipation Maximum-rated value of power dissipation resulting from all sources, including transients and standby current, averaged over a short period of time.
P _{PPM}	Rated Random Recurring Peak Impulse Power Dissipation Maximum-rated value of the product of rated random recurring peak impulse current (I_{PPM}) multiplies by specified maximum clamping voltage (V_{C}).
Сл	Capacitance Capacitance across the TVS measured at a specified frequency and voltage.
V _{FS}	Peak Forward Surge Voltage Peak voltage across an TVS for a specified forward surge current (I_{FS}) and time duration. NOTE: Also shown as $V_{F.}$
I _{FS}	Forward Surge Current Pulsed current through TVS in the forward conducting region. NOTE: Also shown as I _{F.}
α _{V(BR)}	Temperature Coefficient of Breakdown Voltage The change of breakdown voltage divided by the change of temperature.
I _{PP}	Peak pulse Current Peak pulse current value applied across the TVS to determine the clamping voltage $V_{\mathbb{C}}$ for a specified wave shape.
I T	Pulsed D.C. Test Current Test current for measurement of the breakdown voltage $V_{\rm BR}$. This is defined by the manufacturer and usually given in milliamperes with a pulse duration of less than 40 ms. NOTE: Also shown as $I_{\rm BR}$.

-(GB-T 18802.321 / IEC 61643-321 / JESD210A)



Transient Voltage Suppression Diodes

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Usage

- TVS must be operated in the specified ambient temp.
- Do not clean the TVS with strong polar solvent such as ketone, esters, benzene and halogenated hydrocarbon, to avoid damaging the encapsulating layer.
- 3. Please do not apply severe vibration, shock or pressure to TVS, to avoid element cracking.

Replacement

- If TVS is visually damaged, please replace it.
- TVS is a non-repairable product. For safety sake, please use equivalent TVS for replacement.

Storage

- 1. Storage Temp. Range: (-55 to 150) °C.
- Do not store the TVS at the high temp., high humidity or corrosive gas environment, to avoid influencing the solder- ability of the lead wires. The product shall be used up within 1 year after receiving the goods.

Environmental Conditions

- 1. TVS should not be exposed to the open air, nor direct sunshine.
- 2. TVS should avoid rain, water vapor or other condition of high temp. and high humidity.
- TVS should avoid sand dust, salt mist, or other harmful gases.

Max. Typical Capacitance of TVS

The typical capacitance of TVS is listed in the specifications. Designers may refer to it when designing TVS in High frequency circuit.

Installation Mechanical Stress

- 1. Do not knock TVS when installing, to avoid mechanical damage.
- 2. Please do not apply severe vibration, shock or pressure to TVS, to avoid surface resin or element cracking.

TVS Diodes
Transient Voltage Suppression Diodes

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Transient Voltage Suppressor (Surface Mount) Features Overview

	^								,	^
DO-221	AC O	0	0	0	0	SMA6L	0	0	0	
υ DO-214	AA O	0	0	0	0	0	SACB	SMBJ	P6SMB	
DO-214 DO-214 DO-214 DO-214 SOD-123	АВ									Series
DO-214	AC O	0	SMAJ	P4SMA	SMA6J	0	0	0	0	ies
SOD-123	SMF SMF	P4SMF								
SMTO-2	218 0	0	0	0	0	0	0	0	0	
Product Outl (mm)	ine 57.7.	3.65		5.04		5.20 09 X		5.40		
V _R / V _{WM} (V Reverse Stand-off Vo	5.0 ~ 250	5.0 ~ 85	5.0 ~ 440	5.8 ~ 468	5.0 -	~ 250	5.0 ~ 50	5.0 ~ 440	5.8 ~ 512	
PPPM (W) (10/1000 µs Rated Peak ImPul Power Dissipatio	5) 200 se n		400		6	600 500			00	
PPM (KA)(8/20 Rated Peak ImPulse C	µs) urrent				0					
Operating Temperatu (°C)	re	-55 to +150								

TVS Diodes

Transient Voltage Suppression Diodes

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Transient Voltage Suppressor (Surface Mount) Features Overview

	1	\	(-	,						,	^
	DO-221AC	0	0	0	0	0	0	0	0	0	
be	DO-214AA	0	0	0	0	0	0	0	0	0	
Package Type	DO-214AB	SMCJ	1.5SMC	3.0SMCJ	SMDJ	5.0SMDJ			0		Series
ckag	DO-214AC	0	0	0	0	0	0	0	0	0	ies
Pa	SOD-123FL								0		
	SMTO-218	0	0	0	0	0	SPC1	SPC3	SPC6	SPC10	→
Proo	duct Outline (mm)			7.94				7.09	8.27		
V i Revers	R / V _{WM} (V) se Stand-off Voltage	5.0 ~ 440	5.8 ~ 512	5.0 ~	- 440	12 ~ 170	380 / 430	66 58 ~ 76		58 ~ 86	
(10 Rate Po	PPPM (W) 0/1000 μs) ed Peak ImPulse wer Dissipation	15	500	30	000	5000			0		
PPM (Rated P	(kA)(8/20 µs) eak ImPulse Current	0					1	3	6	10	
C Te	Operating mperature (°C)			-55 to +150			-55 to +125				

Transient Voltage Suppressor (Axial Lead) Features Overview

5.0SMDJ Series

TVS Diodes Transient Voltage Suppression Diodes

	/	^														/	\
	DO-201	0	0	0	1.5KE	LCE	0	0	0	0	0	0	0	0	0	0	
Package Type	DO-41	P4KE															4.0
	DO-15	0	SAC	P6KE	0	0	0	0	0	0	0	0	0	0	0	0	Series
	P600	0					5KP	15KPA	20KPA	30KPA							-
Ra	adial lead	0	0	0	0	0	0	0	0	0	SPCL1	SPCL3	SPCL6	SPCL10	SPCL15	SPCL20	→
Product Outline (mm)		9 ± 4.65 ± 42.35 × 55.45 × 55.45	Ф3.10 02 °C	57.50	Φ5.05 Ω Ω Θ Φ1.00	59.15		Φ8.85 98 80	59.65		20.48	17.00	2	0.48	14.50	2.00	
V R/N Reverse Sta	V _{WM} (V) and-off Voltage	5.8 ~ 468	5.0 ~ 50	5.8 ~ 512	5.8 ~ 512	6.5 ~ 90	5.0 ~ 250	17 ~ 280	20 ~ 300	28 ~ 360	76	15 ~ 430	30 ~ 430	15 ~ 530	58 ~ 380	16 ~ 76	
PPI (10/1 Rated Po Power	PPPM (W) (10/1000 µs) Rated Peak ImPulse Power Dissipation		500	600	1500		5000	15000	20000	30000		0					
/PPM (kA)(8/20 µs) Rated Peak ImPulse Current		0										3	6	10	15	20	
Temp	erating perature °C)	-55 to +150								-55 to +125							

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